



Product Change Notification

Effective: Aug-19, 2015

Modification Description:

The brightness specification of LTW-E670DS will be re-modified by adding one high BIN.

Modification Reason:

Due to the blue chip optical power increased, this IV BIN 3550-4500mcd is about 10% output. Lite-On would like to add high IV BIN 3550-4500mcd, as below new IV BIN specification.

Old IV spec.

IV Spec Table		
IV Bin	IV (mcd) at IF=30mA	
	MIN.	MAX.
W2	1400	1800
X1	1800	2240
X2	2240	2800
Y1	2800	3550

New IV spec.

IV Spec Table		
IV Bin	IV (mcd) at If = 30mA	
	Min.	Max.
W2	1400	1800
X1	1800	2240
X2	2240	2800
Y1	2800	3550
Y2	3550	4500

Impact of Modification:

Part Number: LTW-E670DS

Vincent Lin

ALED LOB, OPTO SBG, Lite-On Technology Corp.

Tel: 886-2-2222-6181 Ext 8292

Approver: _____

Date: _____